



Attorney's Docket No.: 07977/097003/US3176D1D1

44/172/1m
R. Kenig
2/20/01

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : H. Zhang
Serial No.: 09/804,654
Filed : March 12, 2001
Title : SEMICONDUCTOR DEVICE AND METHOD OF MANUFACTURING THE SAME

Art Unit : Unknown
Examiner : Unknown

Commissioner for Patents
Washington, D.C. 20231

PRELIMINARY AMENDMENT

Sir:

Prior to initial examination, kindly amend the above-identified divisional application as follows.

In the Claims:

Please add the following new claims.

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--2. (New) A method of manufacturing a semiconductor device comprising the steps of:

A1 forming a semiconductor film comprising amorphous silicon on an insulating surface, said semiconductor film having a first region and a second region;

CERTIFICATE OF MAILING BY FIRST CLASS MAIL

I hereby certify under 37 CFR §1.8(a) that this correspondence is being deposited with the United States Postal Service as first class mail with sufficient postage on the date indicated below and is addressed to the Commissioner for Patents, Washington, D.C. 20231.

April 10, 2001

Date of Deposit

Signature

Susan Regan

Susan Regan

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